

Preliminary Datasheet

N-Channel 30-V (D-S) MOSFET

FEATURES

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

PRODUCTY SUMMARY					
V _{DS}	R	$_{DS(on)} m(\Omega)$	$I_D(A)$		
30	30	Rdson @10V	6.4		
30	50	Rdson @4.5V	5.0		

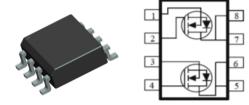
Application

- ■Portable Devices
- ■Consumer Electronics
- ■Consumer Electronics

Mechanical

●Case: SOP-8-Dual Package

SOP-8-Dual



Packing Information

Package	Packing		
SOP-8-Dual	3K/13" Reel		

Maximum Ratings (T _A =25°C unless otherwise specified)						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage	V_{DS}	30	V			
Gate-Source Voltage	V_{GS}	±20	V			
Continuous Drain Current 1)	I _D	5	А			
Maximum Power Dissipation	P _D	1.2	W			
Pulsed Drain Current 2)	I _{DM}	20	А			
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C			

Typical Thermal Resistance					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	110	°C/W		

Note:

R0JA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper



Electrical Characteristics (T _A = 25°C UNLESS OTHERWISE NOTED)						
Characteristics	Symbol	Test Condition	Limits			Heit
Cital acteristics	Symbol	Test Condition	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	B _{VDSS}	VGS = 0V, I _D =250uA	30	1	-	V
Gate Threshold Voltage	$V_{GS(th)}$	VDS=VGS, I _D =250uA	1	-	2.5	V
Drain-Source On-State Resistance	R	V _{GS} =10.0V, I _D =6.4A		21	30	mΩ
Dialii-Source Oil-State Nesistance	R _{DS(on)}	VGS=4.5V, ID=5.0A		35	50	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	VDS=30V, VGS=0V			1.0	uA
Gate-Source Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V			±100	nA
		Dynamic ³⁾				
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =4.5A, V _{GS} =10V ^(Note 1,2)	-	4	-	nC
Gate-Source Charge	Q_gs	VDS=-15V, ID=4.5A, VGS=4.5V (Note 1,2)	-	1.4	-	nC
Gate-Drain Charge	Q_{gd}	VDS=-15V, ID=4.5A, VGS=4.5V (Note 1,2)	-	2.1	-	nC
Input Capacitance	C _{iss}		-	360	-	pF
Output Capacitance	C _{oss}	V_{DS} =15V, V_{GS} =0V, f=1.0MHZ	-	56	-	pF
Reverse Transfer Capacitance	C_{rss}		-	46	-	pF
		Switching				
Turn-On Delay Time	t _{d(on)}		ı	3	-	ns
Turn-On Rise Time	t _r	V _{DD} =15V, I _D =2.25A,	-	6	-	ns
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,RG=10 Ω (Note 1,2)	-	17	-	ns
Turn-Off Fall Time	t _f		-	5	-	ns
Drain-Source Diode						
Diode Forward Voltage	V_{SD}	I _S =-0.8A, V _{GS} =0V	-	-	1.2	V

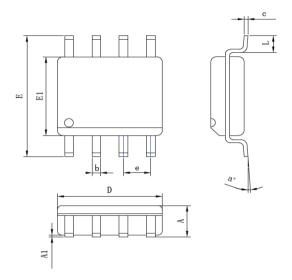
Note:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Fused current that based on wire numbers and diameter
- 3. Guaranteed by design, not subject to production testing.

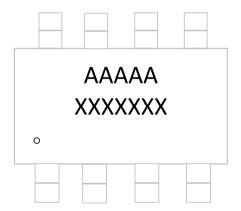


Package Outline Dimensions (inches and millimeters)

SOP-8						
	Dimensions					
SYMBOL	Millimeters		Inches			
	Min	Max	Min	Max		
Α	1	1.75		0.069		
A1	0.10	0.23	0.004	0.009		
b	0.35	0.48	0.014	0.019		
С	0.19	0.25	0.007	0.010		
D	4.70	5.10	0.185	0.201		
Е	5.80	6.20	0.228	0.244		
E1	3.70	4.10	0.146	0.161		
е	1.27bsc					
L	0.50	0.80	0.020	0.031		
a˚	0 °	8 °	0 °	8 °		



Marking Information



First line:

AAAAA = Product number

XXXXXXX = Tracking number

Third line:Gate Pin Point

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